

NIS5132

12 V eFuse

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- Integrated Power Device
 - Internal Latching Thermally Protected
 - No External Current Shunt Required
 - 9V to 18V Input Range
 - Internal Charge Pump
 - Internal Undervoltage Lockout Circuit
 - Internal Overvoltage Clamp
 - ESD Ratings: Human Body Model (HBM); 1500V, Machine Model (MM); 200V
 - These are Pb-Free Devices
 - Auto Retry Option
For more features, see the data sheet
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- Mother Board Power Management
 - Hard Drives